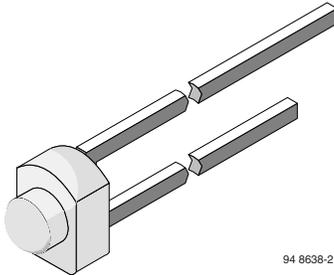


## Infrared Emitting Diode, 950 nm, GaAs



94 8638-2

### FEATURES

- Package type: leaded
- Package form: T-3/4
- Dimensions (in mm):  $\varnothing$  1.8
- Peak wavelength:  $\lambda_p = 950$  nm
- High reliability
- Angle of half intensity:  $\varphi = \pm 12^\circ$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Package matches with detector BPW17N
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


**RoHS**  
COMPLIANT

### DESCRIPTION

CQY37N is an infrared, 950 nm emitting diode in GaAs technology molded in a miniature, clear plastic package with lens.

### APPLICATIONS

- Radiation source in near infrared range

### PRODUCT SUMMARY

COMPONENT	$I_e$ (mW/sr)	$\varphi$ (deg)	$\lambda_p$ (nm)	$t_r$ (ns)
CQY37N	5	$\pm 12$	950	800

#### Note

- Test conditions see table "Basic Characteristics"

### ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
CQY37N	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-3/4

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_R$	5	V
Forward current		$I_F$	100	mA
Surge forward current	$t_p \leq 100 \mu\text{s}$	$I_{FSM}$	2	A
Power dissipation		$P_V$	160	mW
Junction temperature		$T_j$	100	$^\circ\text{C}$
Operating temperature range		$T_{amb}$	- 25 to + 85	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	- 25 to + 100	$^\circ\text{C}$
Soldering temperature	$t \leq 3$ s	$T_{sd}$	245	$^\circ\text{C}$
Thermal resistance junction/ambient	Leads not soldered	$R_{thJA}$	450	K/W

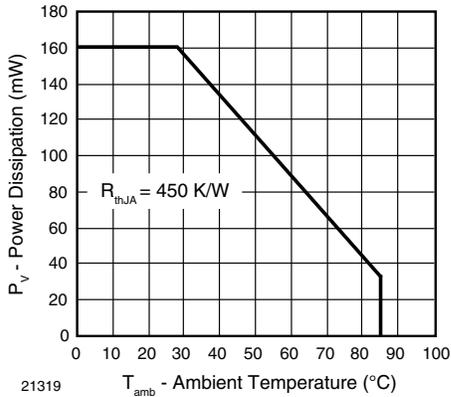


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

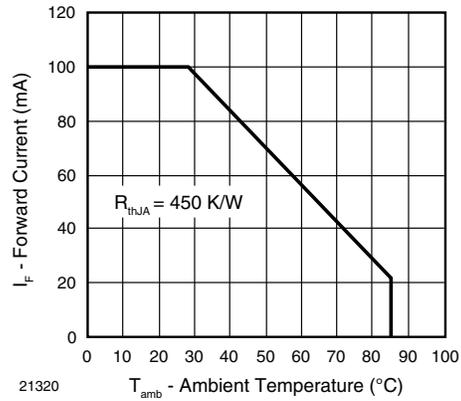


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 50\text{ mA}$ , $t_p \leq 20\text{ ms}$	$V_F$		1.3	1.6	V
Temperature coefficient of $V_F$	$I_F = 100\text{ mA}$	$TK_{V_F}$		- 1.3		mV/K
Breakdown voltage	$I_R = 100\text{ }\mu\text{A}$	$V_{(BR)}$	5			$\mu\text{A}$
Junction capacitance	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$	$C_j$		50		pF
Radiant intensity	$I_F = 50\text{ mA}$ , $t_p \leq 20\text{ ms}$	$I_e$	2.2	5	11	mW/sr
Radiant power	$I_F = 50\text{ mA}$ , $t_p \leq 20\text{ ms}$	$\phi_e$	4.8	10	17.8	mW
Temperature coefficient of $\phi_e$	$I_F = 50\text{ mA}$	$TK_{\phi_e}$		- 0.8		%/K
Angle of half intensity		$\phi$		$\pm 12$		deg
Peak wavelength	$I_F = 50\text{ mA}$	$\lambda_p$		950		nm
Spectral bandwidth	$I_F = 50\text{ mA}$	$\Delta\lambda$		50		nm
Rise time	$I_F = 100\text{ mA}$	$t_r$		800		ns
	$I_F = 1.5\text{ A}$ , $t_p/T = 0.01$ , $t_p \leq 10\text{ }\mu\text{s}$	$t_r$		400		ns
Virtual source diameter		$d$		1.2		mm

**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

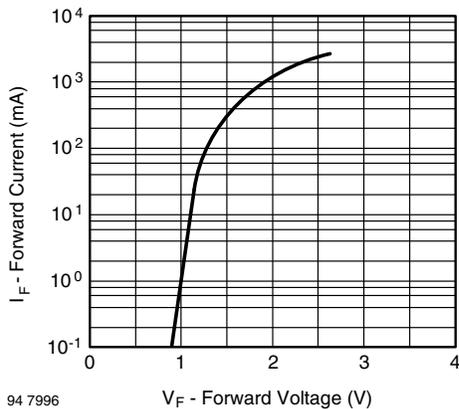


Fig. 3 - Forward Current vs. Forward Voltage

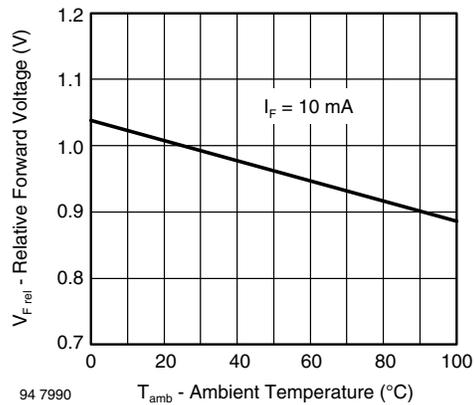


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

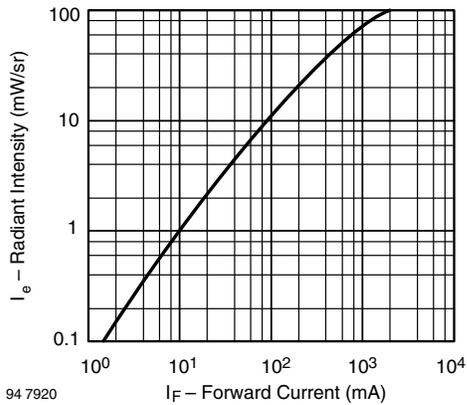


Fig. 5 - Radiant Intensity vs. Forward Current

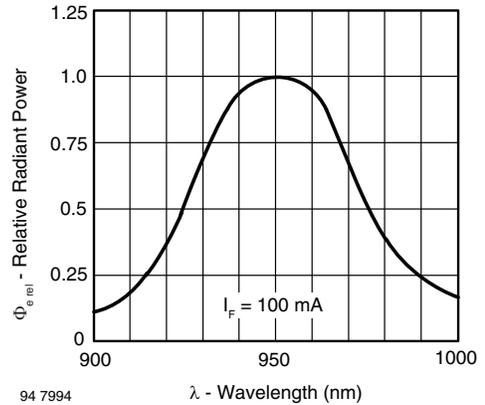


Fig. 8 - Relative Radiant Power vs. Wavelength

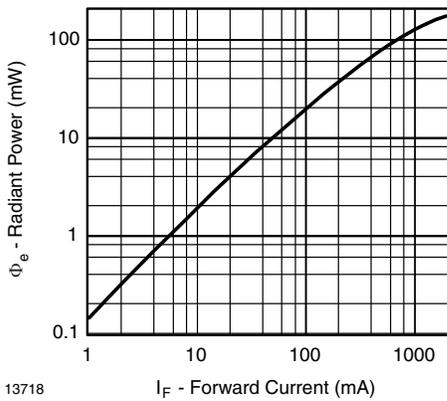


Fig. 6 - Radiant Power vs. Forward Current

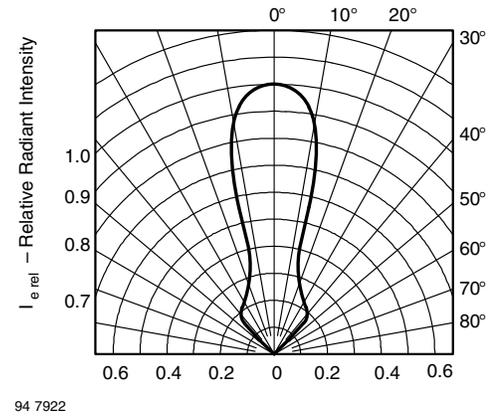


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

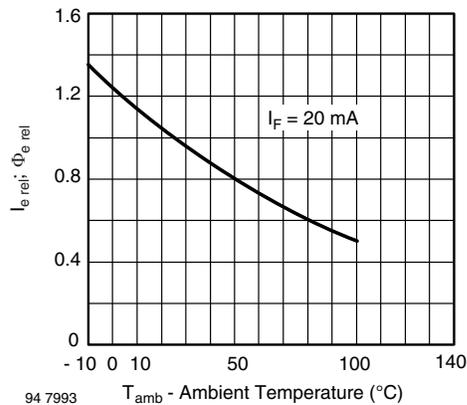


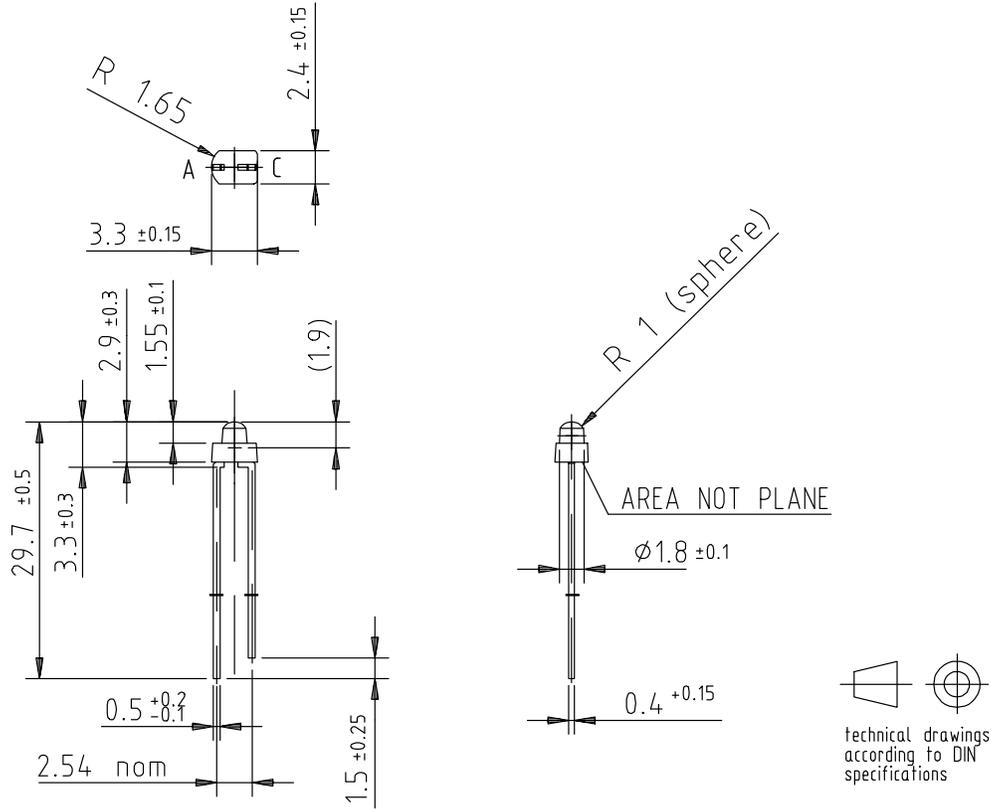
Fig. 7 - Relative Radiant Intensity/Power vs. Ambient Temperature

# CQY37N

Vishay Semiconductors Infrared Emitting Diode, 950 nm,  
GaAs



## PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5052.01-4  
Issue: 1; 12.10.95  
95 11262



## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.